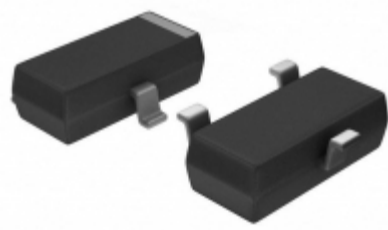








	<h2 style="color: red;">FJV4113RMTF</h2>
	<p><b>Hersteller-Teilenummer:</b> FJV4113RMTF</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> TRANS PREBIAS PNP 200MW SOT23-3</p> <p><b>Datenblätter:</b> <a href="#">1.FJV4113RMTF.pdf</a> <a href="#">2.FJV4113RMTF.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 389516 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FJV4113RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	389516 pcs Stock
Hersteller Standard Vorlaufzeit	2 Weeks
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Cut Tape (CT)
Basisteilenummer	FJV4113
Widerstand - Basis (R1)	2.2 kOhms
Widerstand - Emitterbasis (R2)	47 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJV4113RMTFCT

FJV4113RMTF ist neu im Original, Suche FJV4113RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4113RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4113RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FJV4111RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p><b>FJV4111RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p><b>FJV4112RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p><b>FJV4114RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>
 <p><b>FJV42MTF</b> AMI Semiconductor / ON Semiconductor TRANS NPN 350V 0.5A SOT-23</p>	 <p><b>FJV4113RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p><b>FJV4112RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p><b>FJV4114RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>

heiße Teile

Mehr

⊕ FJV3108RMTF	↔ FJV3108RMTF	⇒ FJV3109R	D FJV3109RMTF	⇒ FJV3109RMTF
⊕ FJV3110RMTF	⊕ FJV3110RMTF	D FJV3111RMTF	⇒ FJV3111RMTF	⇒ FJV3112RMTF
⊕ FJV3112RMTF	⊕ FJV3113RMTF	⊕ FJV3113RMTF	↔ FJV3114RMTF	⇒ FJV3114RMTF
D FJV3115RMTF	⊕ FJV3115RMTF	⊕ FJV4101RMTF	⊕ FJV4101RMTF	⇒ FJV4102RLIMTF
⇒ FJV4102RMTF	↔ FJV4102RMTF	⊕ FJV4103RMTF	⊕ FJV4103RMTF	⇒ FJV4104RMTF
↔ FJV4104RMTF	⇒ FJV4105RMTF	D FJV4105RMTF	⊕ FJV4106RMTF	⊕ FJV4106RMTF
⊕ FJV4107RMTF	D FJV4107RMTF	⇒ FJV4108RMTF	↔ FJV4108RMTF	⇒ FJV4109RMTF
⊕ FJV4109RMTF	⊕ FJV4110RMTF	↔ FJV4110RMTF	⇒ FJV4111RMTF	⇒ FJV4111RMTF
⊕ FJV4112RMTF	⊕ FJV4112RMTF	⊕ FJV4113RMTF	D FJV4114RMTF	⇒ FJV4114RMTF
↔ FJV42MTF	⊕ FJV42MTF	⊕ FJV992EMTF	⊕ FJV992PMTF	⇒ FJV992PMTF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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